

Depletion-Mode Power MOSFET

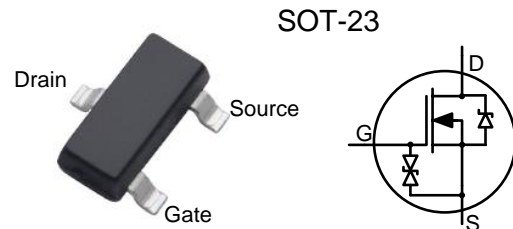
General Features

- ESD improved Capability
- Depletion Mode (Normally On)
- Proprietary Advanced Planar Technology
- Rugged Polysilicon Gate Cell Structure
- Fast Switching Speed
- RoHS Compliant
- Halogen-free available

BV _{DSX}	R _{DS(ON)} (Max.)	I _{DSS,min}
600V	700 Ω	5mA

Applications

- Normally-on Switches
- SMPS Start-up Circuit
- Linear Amplifier
- Converters
- Constant Current Source
- Telecom



Ordering Information

Part Number	Package	Marking	Remark
DMZ6005EH	SOT-23	605E	Halogen Free

Absolute Maximum Ratings

TA =25°C unless otherwise specified

Symbol	Parameter	DMZ6005EH	Unit
V _{DSX}	Drain-to-Source Voltage ^[1]	600	V
V _{DGX}	Drain-to-Gate Voltage ^[1]	600	V
I _D	Continuous Drain Current	0.02	A
I _{DM}	Pulsed Drain Current ^[2]	0.08	
P _D	Power Dissipation	0.50	W
V _{GS}	Gate-to-Source Voltage	±20	V
T _L	Soldering Temperature Distance of 1.6mm from case for 10 seconds	300	°C
T _J and T _{STG}	Operating and Storage Temperature Range	-55 to 150	

Caution: Stresses greater than those listed in the “Absolute Maximum Ratings” may cause permanent damage to the device.

Thermal Characteristics

Symbol	Parameter	DMZ6005EH	Unit
R _{θJA}	Thermal Resistance, Junction-to-Ambient	250	K/W

Electrical Characteristics

OFF Characteristics

 $T_A = 25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
BV_{DSX}	Drain-to-Source Breakdown Voltage	600	--	--	V	$V_{GS} = -5V, I_D = 250\mu A$
$I_{D(OFF)}$	Drain-to-Source Leakage Current	--	--	0.1	μA	$V_{DS} = 600V, V_{GS} = -5V$
		--	--	10	μA	$V_{DS} = 600V, V_{GS} = -5V$ $T_J = 125^\circ\text{C}$
I_{GSS}	Gate-to-Source Leakage Current	--	--	20	μA	$V_{GS} = +20V, V_{DS} = 0V$
		--	--	-20		$V_{GS} = -20V, V_{DS} = 0V$

ON Characteristics

 $T_A = 25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
I_{DSS}	Saturated Drain-to-Source Current	5	--	25	mA	$V_{GS} = 0V, V_{DS} = 25V$
$R_{DS(ON)}$	Static Drain-to-Source On-Resistance	--	500	700	Ω	$V_{GS} = 0V, I_D = 3mA$ ^[3]
$V_{GS(OFF)}$	Gate-to-Source Cut-off Voltage	-2.39	--	-1.96	V	$V_{DS} = 3V, I_D = 8\mu A$
gfs	Forward Transconductance	--	15.4	--	mS	$V_{DS} = 10V, I_D = 5mA$

Dynamic Characteristics

Essentially independent of operating temperature

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
C_{ISS}	Input Capacitance	--	12.3	--	pF	$V_{GS} = -5V$ $V_{DS} = 25V$ $f = 1.0MHz$
C_{OSS}	Output Capacitance	--	2.6	--		
C_{RSS}	Reverse Transfer Capacitance	--	1.8	--		
Q_G	Total Gate Charge	--	1.55	--	nC	$V_{GS} = -5V \sim 5V$ $V_{DS} = 300V, I_D = 7mA$
Q_{GS}	Gate-to-Source Charge	--	0.12	--		
Q_{GD}	Gate-to-Drain (Miller) Charge	--	0.56	--		

Resistive Switching Characteristics

Essentially independent of operating temperature

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
$t_{d(ON)}$	Turn-on Delay Time	--	4	--	ns	$V_{GS} = -5V \sim 5V$ $V_{DD} = 300V, I_D = 7mA$ $R_G = 20\Omega$
t_{rise}	Rise Time	--	9	--		
$t_{d(OFF)}$	Turn-off Delay Time	--	14	--		
t_{fall}	Fall Time	--	84	--		

Source-Drain Diode Characteristics

TA =25°C unless otherwise specified

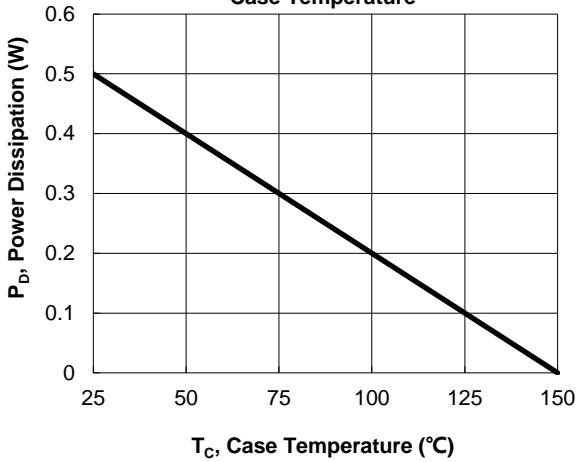
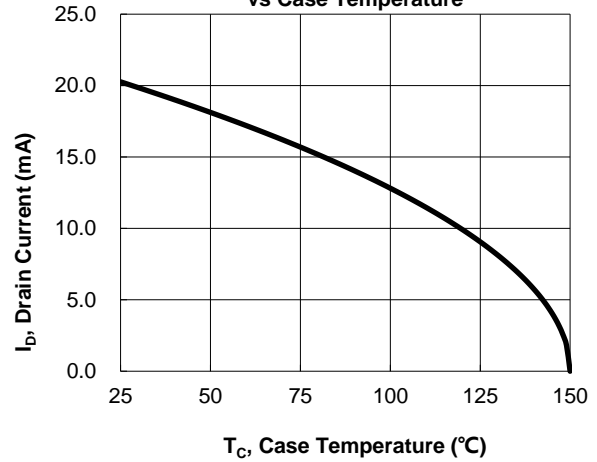
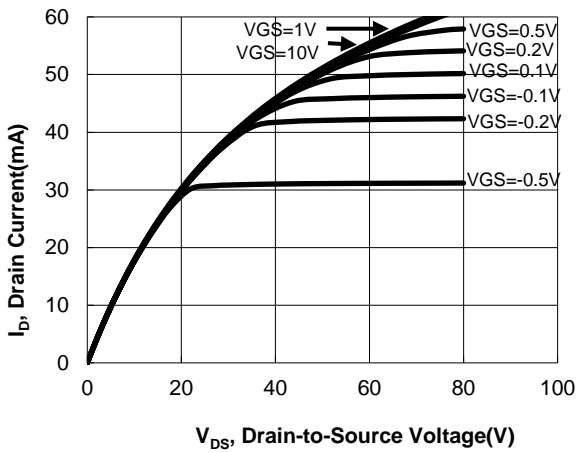
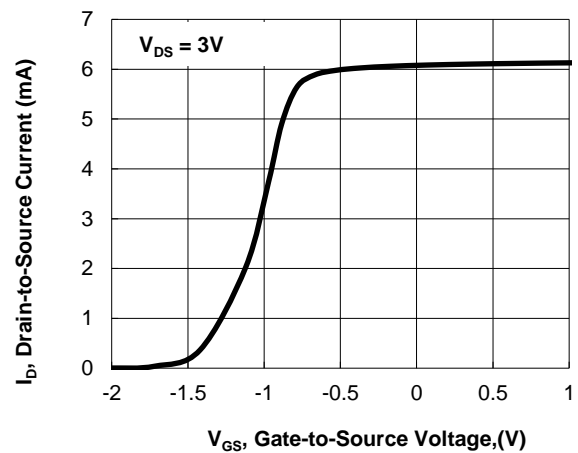
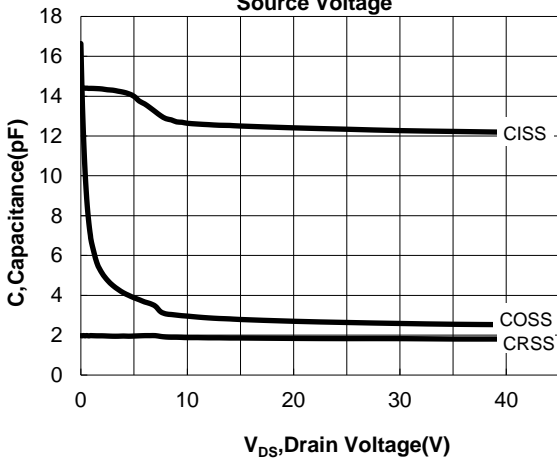
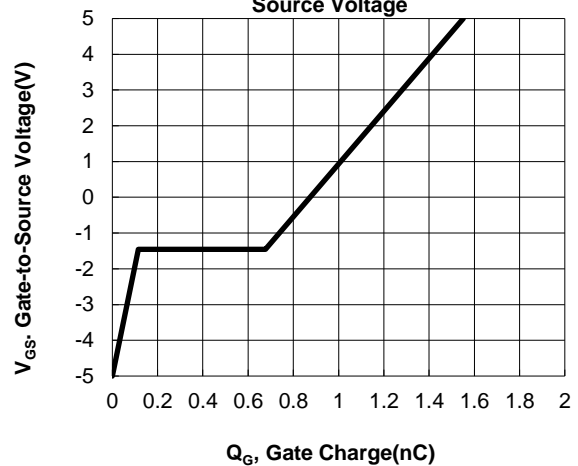
Symbol	Parameter	Min	Typ.	Max.	Units	Test Conditions
V _{SD}	Diode Forward Voltage	--	--	1.2	V	I _{SD} =3.0 mA, V _{GS} = -10 V

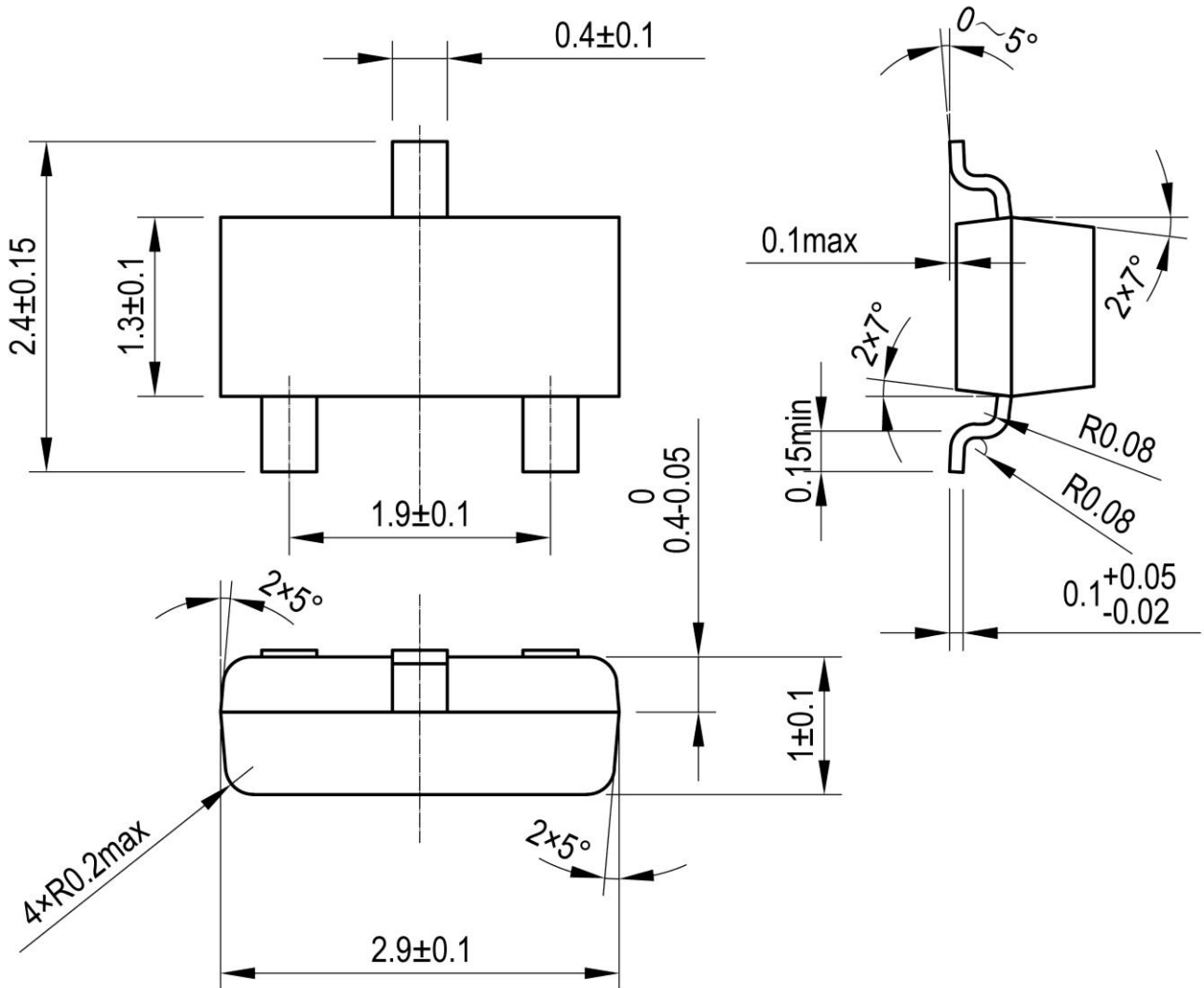
NOTE:

[1] T_J=+25°C to +150°C

[2] Repetitive rating, pulse width limited by maximum junction temperature.

[3] Pulse width≤380μs;duty cycle≤2%.

Figure 1. Maximum Power Dissipation vs. Case Temperature

Figure 2. Maximum Continuous Drain Current vs Case Temperature

Figure 3. Typical Output Characteristics

Figure 4. Typical Transfer Characteristics

Figure 5. Typical Capacitance vs. Drain-to-Source Voltage

Figure 6. Typical Gate Charge vs. Gate-to-Source Voltage


Package Dimensions**SOT-23**



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